

74HC594-Q100; 74HCT594-Q100

8-bit shift register with output register

Rev. 5 — 19 March 2023

Product data sheet

1. General description

The 74HC594-Q100; 74HCT594-Q100 is an 8-bit serial-in/serial or parallel-out shift register with a storage register. Separate clock and reset inputs are provided on both shift and storage registers. The device features a serial input (DS) and a serial output (Q7S) to enable cascading. Data is shifted on the LOW-to-HIGH transitions of the SHCP input, and the data in the shift register is transferred to the storage register on a LOW-to-HIGH transition of the STCP input. If both clocks are connected together, the shift register will always be one clock pulse ahead of the storage register. A LOW level on one of the two register reset pins (SHR and STR) will clear the corresponding register. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Synchronous serial input and output
- 8-bit parallel output
- Shift and storage registers have independent direct clear and clocks
- Independent clocks for shift and storage registers
- 100 MHz (typical)
- Wide supply voltage range from 2.0 V to 6.0 V
- CMOS low power dissipation
- High noise immunity
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Input levels:
 - For 74HC594-Q100: CMOS level
 - For 74HCT594-Q100: TTL level
- Complies with JEDEC standards
 - JESD8C (2.7 V to 3.6 V)
 - JESD7A (2.0 V to 6.0 V)
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- DHVQFN package with Side-Wettable Flanks enabling Automatic Optical Inspection (AOI) of solder joints

3. Applications

- Serial-to parallel data conversion
- Remote control holding register

4. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74HC594D-Q100 74HCT594D-Q100	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HC594PW-Q100	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1
74HC594BQ-Q100	-40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 × 3.5 × 0.85 mm	SOT763-1

5. Functional diagram

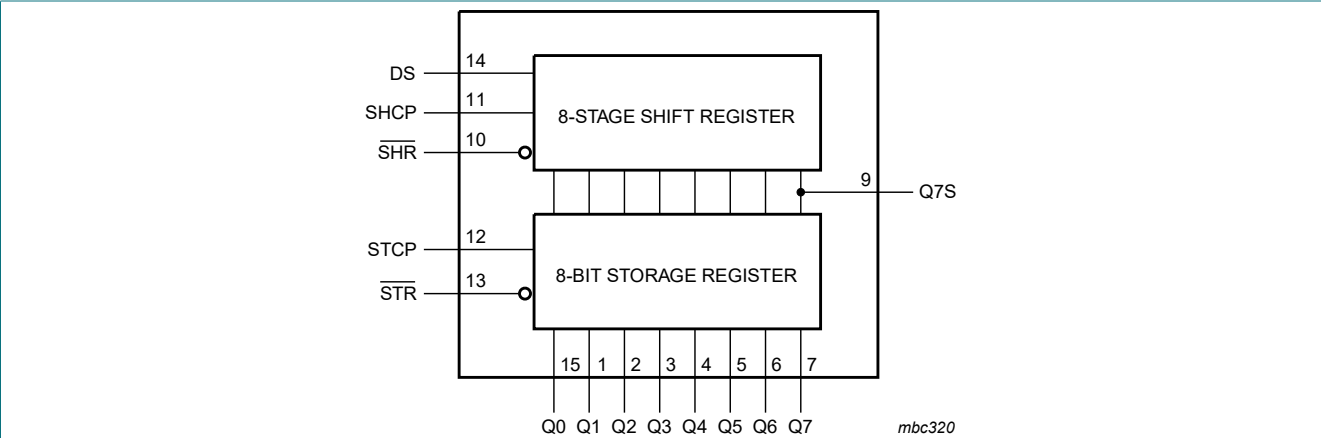


Fig. 1. Functional diagram

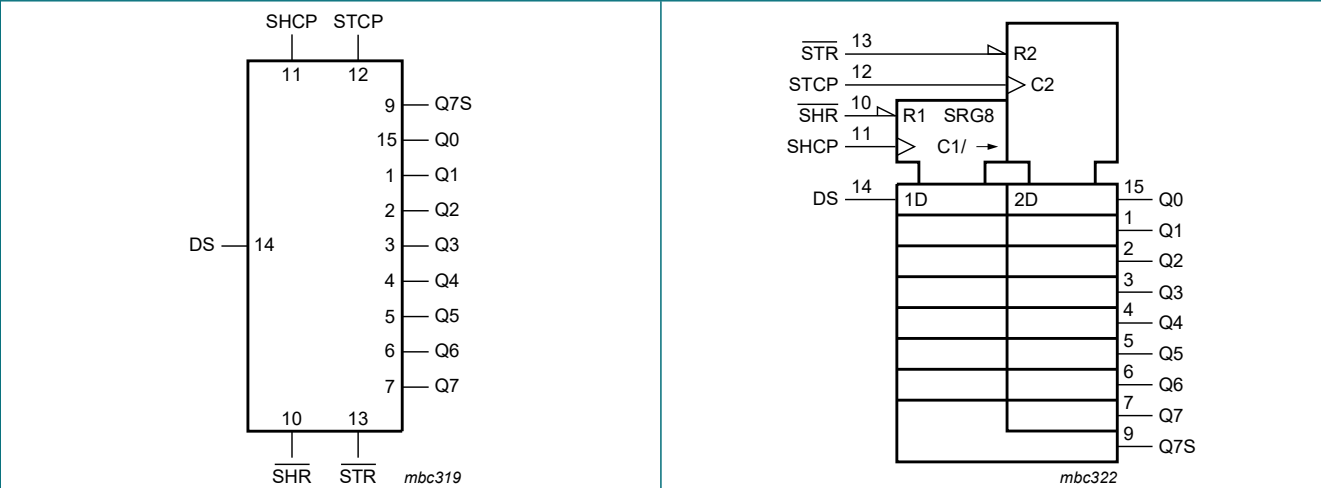


Fig. 2. Logic symbol

Fig. 3. IEC logic symbol

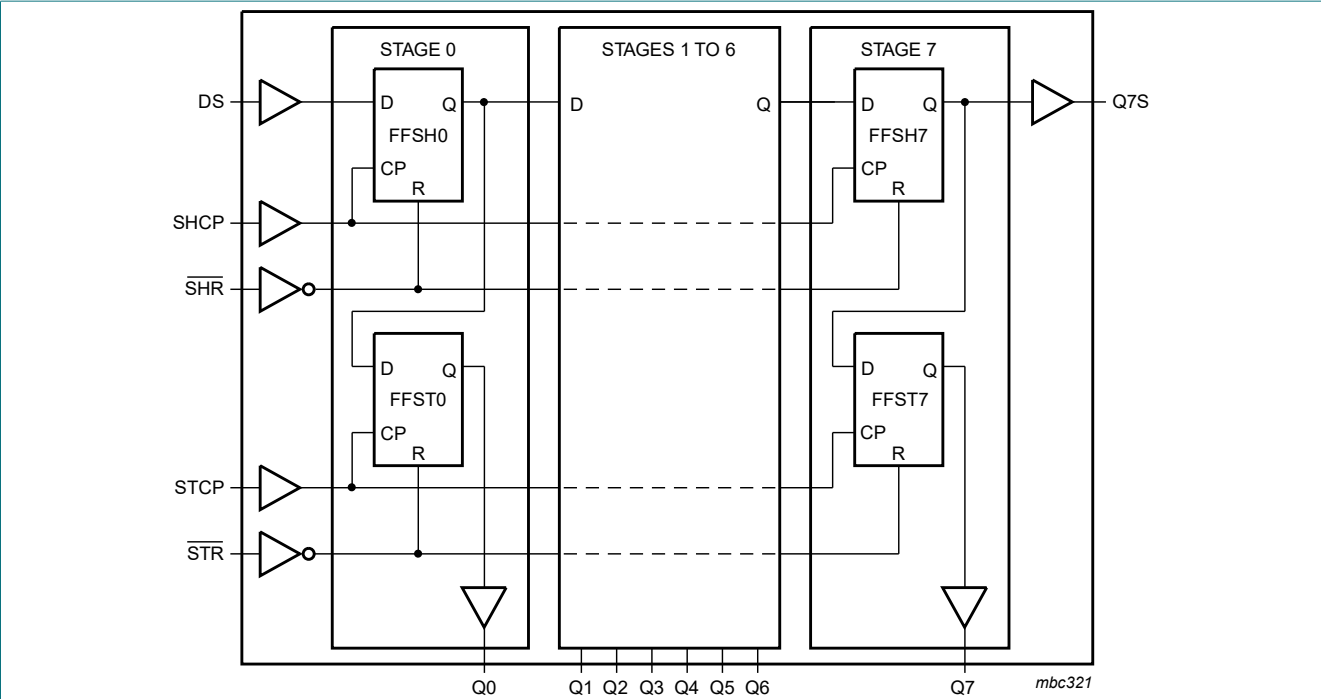


Fig. 4. Logic diagram

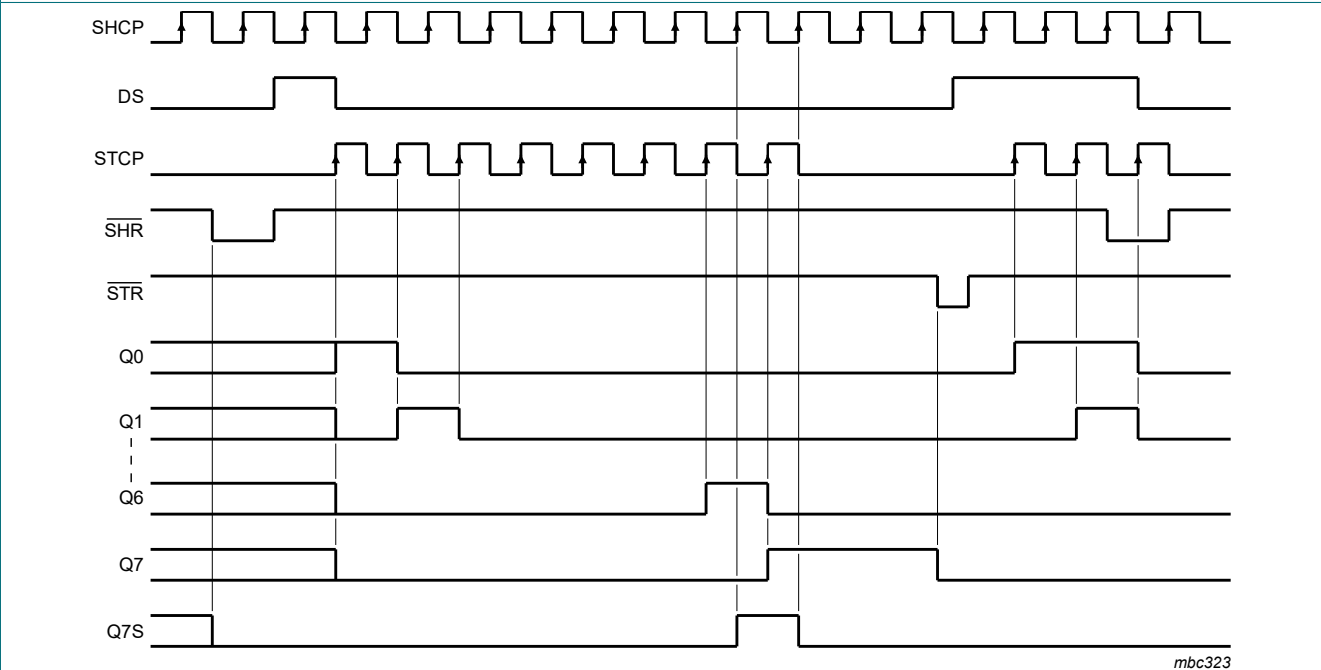
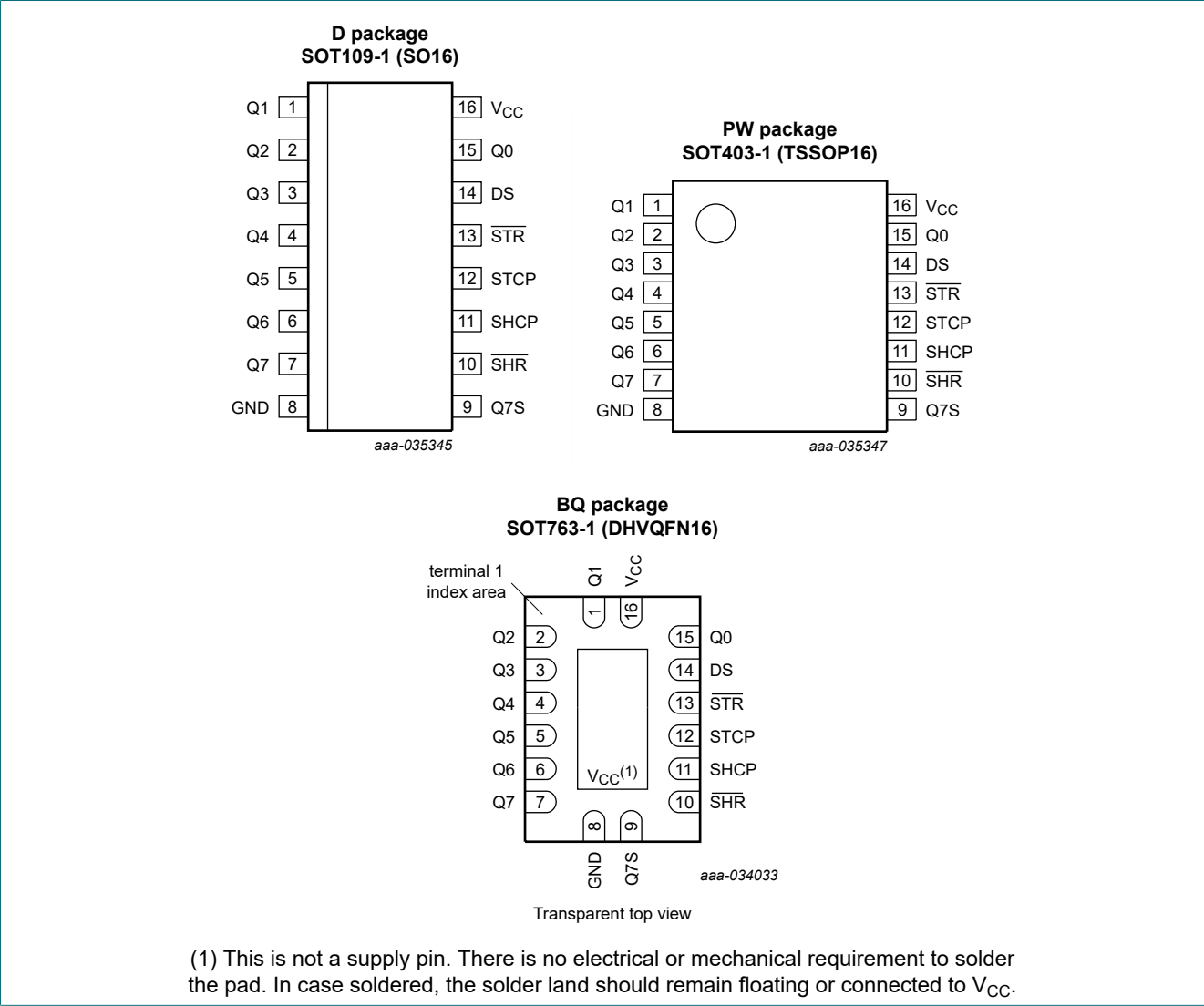


Fig. 5. Timing diagram

6. Pinning information

6.1. Pinning



6.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
Q0, Q1, Q2, Q3, Q4, Q5, Q6, Q7	15, 1, 2, 3, 4, 5, 6, 7	parallel data output
GND	8	ground (0 V)
Q7S	9	serial data output
SHR	10	shift register reset (active LOW)
SHCP	11	shift register clock input
STCP	12	storage register clock input
STR	13	storage register reset (active LOW)
DS	14	serial data input
V _{CC}	16	supply voltage

7. Functional description

Table 3. Function table

H = HIGH voltage level; L = LOW voltage level; ↑ = LOW-to-HIGH transition; X = don't care.

Function	Input				
	SHR	STR	SHCP	STCP	DS
Clear shift register	L	X	X	X	X
Clear storage register	X	L	X	X	X
Load DS into shift register stage 0, advance previous stage data to the next stage	H	X	↑	X	H or L
Transfer shift register data to storage register and outputs Qn	X	H	X	↑	X
Shift register one count pulse ahead of storage register	H	H	↑	↑	X

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7.0	V
I _{IK}	input clamping current	V _I < -0.5 V or V _I > V _{CC} + 0.5 V [1]	-	±20	mA
I _{OK}	output clamping current	V _O < -0.5 V or V _O > V _{CC} + 0.5 V [1]	-	±20	mA
I _O	output current	V _O = -0.5 V to V _{CC} + 0.5 V			
		Serial data output Q7S	-	±25	mA
		Parallel data output Qn	-	±35	mA
I _{CC}	supply current	Serial data output Q7S	-	50	mA
		Parallel data output Qn	-	70	mA
I _{GND}	ground current	Serial data output Q7S	-	-50	mA
		Parallel data output Qn	-	-70	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C [2]	-	500	mW

- [1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
[2] For SOT109-1 (SO16) package: P_{tot} derates linearly with 12.4 mW/K above 110 °C.
For SOT403-1 (TSSOP16) package: P_{tot} derates linearly with 8.5 mW/K above 91 °C.
For SOT763-1 (DHVQFN16) package: P_{tot} derates linearly with 11.2 mW/K above 106 °C.

9. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	74HC594-Q100			74HCT594-Q100			Unit
			Min	Typ	Max	Min	Typ	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
V _I	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
V _O	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	-	+125	-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
		V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V

10. Static characteristics

Table 6. Static characteristics type 74HC594-Q100

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
T_{amb} = 25 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	1.2	-	V
		V _{CC} = 4.5 V	3.15	2.4	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	0.8	0.5	V
		V _{CC} = 4.5 V	-	2.1	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}				
		Q7S; I _O = -4.0 mA; V _{CC} = 4.5 V	3.98	4.32	-	V
		Q7S; I _O = -5.2 mA; V _{CC} = 6.0 V	5.48	5.81	-	V
		Qn; I _O = -6.0 mA; V _{CC} = 4.5 V	3.98	4.32	-	V
		Qn; I _O = -7.8 mA; V _{CC} = 6.0 V	5.48	5.81	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		Q7S; I _O = 4.0 mA; V _{CC} = 4.5 V	-	0.15	0.26	V
		Q7S; I _O = 5.2 mA; V _{CC} = 6.0 V	-	0.16	0.26	V
		Qn; I _O = 6.0 mA; V _{CC} = 4.5 V	-	0.15	0.26	V
		Qn; I _O = 7.8 mA; V _{CC} = 6.0 V	-	0.16	0.26	V
I _I	input leakage current	V _I = V _{CC} or GND; V _{CC} = 6.0 V	-	-	±0.1	µA
I _{CC}	supply current	V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 6.0 V	-	-	8.0	µA
C _i	input capacitance		-	3.5	-	pF
T_{amb} = -40 °C to +85 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	V
		V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}				
		Q7S; I _O = -4.0 mA; V _{CC} = 4.5 V	3.84	-	-	V
		Q7S; I _O = -5.2 mA; V _{CC} = 6.0 V	5.34	-	-	V
		Qn; I _O = -6.0 mA; V _{CC} = 4.5 V	3.84	-	-	V
		Qn; I _O = -7.8 mA; V _{CC} = 6.0 V	5.34	-	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		Q7S; I _O = 4.0 mA; V _{CC} = 4.5 V	-	-	0.33	V
		Q7S; I _O = 5.2 mA; V _{CC} = 6.0 V	-	-	0.33	V
		Qn; I _O = 6.0 mA; V _{CC} = 4.5 V	-	-	0.33	V
		Qn; I _O = 7.8 mA; V _{CC} = 6.0 V	-	-	0.33	V
I _I	input leakage current	V _I = V _{CC} or GND; V _{CC} = 6.0 V	-	-	±1.0	µA
I _{CC}	supply current	V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 6.0 V	-	-	80	µA

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
T_{amb} = -40 °C to +125 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	V
		V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}				
		Q7S; I _O = -4.0 mA; V _{CC} = 4.5 V	3.7	-	-	V
		Q7S; I _O = -5.2 mA; V _{CC} = 6.0 V	5.2	-	-	V
		Qn; I _O = -6.0 mA; V _{CC} = 4.5 V	3.7	-	-	V
		Qn; I _O = -7.8 mA; V _{CC} = 6.0 V	5.2	-	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		Q7S; I _O = 4.0 mA; V _{CC} = 4.5 V	-	-	0.4	V
		Q7S; I _O = 5.2 mA; V _{CC} = 6.0 V	-	-	0.4	V
		Qn; I _O = 6.0 mA; V _{CC} = 4.5 V	-	-	0.4	V
		Qn; I _O = 7.8 mA; V _{CC} = 6.0 V	-	-	0.4	V
I _I	input leakage current	V _I = V _{CC} or GND; V _{CC} = 6.0 V	-	-	±1.0	µA
I _{CC}	supply current	V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 6.0 V	-	-	160	µA

Table 7. Static characteristics type 74HCT594-Q100

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
T_{amb} = 25 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}				
		Q7S; I _O = -4.0 mA; V _{CC} = 4.5 V	3.98	4.32	-	V
		Qn; I _O = -6.0 mA; V _{CC} = 4.5 V	3.98	4.32	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		Q7S; I _O = 4.0 mA; V _{CC} = 4.5 V	-	0.15	0.26	V
		Qn; I _O = 6.0 mA; V _{CC} = 4.5 V	-	0.16	0.26	V
I _I	input leakage current	V _I = V _{CC} or GND; V _{CC} = 5.5 V	-	-	±0.1	µA
I _{CC}	supply current	V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 5.5 V	-	-	8.0	µA
ΔI _{CC}	additional supply current	per input pin; V _I = V _{CC} - 2.1 V and other inputs at V _{CC} or GND; I _O = 0 A; V _{CC} = 4.5 V to 5.5 V				
		pins SHR, SHCP, STCP, STR	-	150	540	µA
		pin DS	-	25	90	µA
C _i	input capacitance		-	3.5	-	pF

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
T _{amb} = -40 °C to +85 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}				
		Q7S; I _O = -4.0 mA; V _{CC} = 4.5 V	3.84	-	-	V
		Qn; I _O = -6.0 mA; V _{CC} = 4.5 V	3.84	-	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		Q7S; I _O = 4.0 mA; V _{CC} = 4.5 V	-	-	0.33	V
		Qn; I _O = 6.0 mA; V _{CC} = 4.5 V	-	-	0.33	V
I _I	input leakage current	V _I = V _{CC} or GND; V _{CC} = 5.5 V	-	-	±1.0	µA
I _{CC}	supply current	V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 5.5 V	-	-	80	µA
ΔI _{CC}	additional supply current	per input pin; V _I = V _{CC} - 2.1 V and other inputs at V _{CC} or GND; I _O = 0 A; V _{CC} = 4.5 V to 5.5 V				
		pins $\overline{\text{SHR}}$, SHCP, STCP, STR	-	-	675	µA
		pin DS	-	-	112.5	µA
T _{amb} = -40 °C to +125 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}				
		Q7S; I _O = -4.0 mA; V _{CC} = 4.5 V	3.7	-	-	V
		Qn; I _O = -6.0 mA; V _{CC} = 4.5 V	3.7	-	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		Q7S; I _O = 4.0 mA; V _{CC} = 4.5 V	-	-	0.4	V
		Qn; I _O = 6.0 mA; V _{CC} = 4.5 V	-	-	0.4	V
I _I	input leakage current	V _I = V _{CC} or GND; V _{CC} = 5.5 V	-	-	±1.0	µA
I _{CC}	supply current	V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 5.5 V	-	-	160	µA
ΔI _{CC}	additional supply current	per input pin; V _I = V _{CC} - 2.1 V and other inputs at V _{CC} or GND; I _O = 0 A; V _{CC} = 4.5 V to 5.5 V				
		pins $\overline{\text{SHR}}$, SHCP, STCP, $\overline{\text{STR}}$	-	-	735	µA
		pin DS	-	-	122.5	µA

11. Dynamic characteristics

Table 8. Dynamic characteristics type 74HC594-Q100

$GND = 0\text{ V}$; $t_r = t_f = 6\text{ ns}$; $C_L = 50\text{ pF}$; For test circuit see [Fig. 12](#).

Symbol	Parameter	Conditions	25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
t_{pd}	propagation delay	SHCP to Q7S; see Fig. 6 [1]								
		$V_{CC} = 2.0\text{ V}$	-	44	150	-	185	-	225	ns
		$V_{CC} = 4.5\text{ V}$	-	16	30	-	37	-	45	ns
		$V_{CC} = 5.0\text{ V}$; $C_L = 15\text{ pF}$	-	13	-	-	-	-	-	ns
		$V_{CC} = 6.0\text{ V}$	-	14	26	-	31	-	38	ns
		STCP to Qn; see Fig. 7								
		$V_{CC} = 2.0\text{ V}$	-	44	150	-	185	-	225	ns
		$V_{CC} = 4.5\text{ V}$	-	16	30	-	37	-	45	ns
		$V_{CC} = 5.0\text{ V}$; $C_L = 15\text{ pF}$	-	13	-	-	-	-	-	ns
		$V_{CC} = 6.0\text{ V}$	-	14	26	-	31	-	38	ns
t_{PHL}	HIGH to LOW propagation delay	SHR to Q7S; see Fig. 10								
		$V_{CC} = 2.0\text{ V}$	-	39	150	-	185	-	225	ns
		$V_{CC} = 4.5\text{ V}$	-	14	30	-	37	-	45	ns
		$V_{CC} = 5.0\text{ V}$; $C_L = 15\text{ pF}$	-	11	-	-	-	-	-	ns
		$V_{CC} = 6.0\text{ V}$	-	12	26	-	31	-	38	ns
		STR to Qn; see Fig. 11								
		$V_{CC} = 2.0\text{ V}$	-	39	125	-	155	-	185	ns
		$V_{CC} = 4.5\text{ V}$	-	14	25	-	31	-	37	ns
		$V_{CC} = 5.0\text{ V}$; $C_L = 15\text{ pF}$	-	11	-	-	-	-	-	ns
		$V_{CC} = 6.0\text{ V}$	-	12	21	-	26	-	31	ns
t_{THL}	HIGH to LOW output transition time	Q7S; see Fig. 6								
		$V_{CC} = 2.0\text{ V}$	-	19	75	-	95	-	110	ns
		$V_{CC} = 4.5\text{ V}$	-	7	15	-	19	-	22	ns
		$V_{CC} = 6.0\text{ V}$	-	6	13	-	16	-	19	ns
		Qn								
		$V_{CC} = 2.0\text{ V}$	-	14	60	-	75	-	90	ns
		$V_{CC} = 4.5\text{ V}$	-	5	12	-	15	-	18	ns
		$V_{CC} = 6.0\text{ V}$	-	4	10	-	13	-	15	ns
t_{TLH}	LOW to HIGH output transition time	Q7S; see Fig. 6								
		$V_{CC} = 2.0\text{ V}$	-	19	75	-	95	-	110	ns
		$V_{CC} = 4.5\text{ V}$	-	7	15	-	19	-	22	ns
		$V_{CC} = 6.0\text{ V}$	-	6	13	-	16	-	19	ns
		Qn								
		$V_{CC} = 2.0\text{ V}$	-	14	60	-	75	-	90	ns
		$V_{CC} = 4.5\text{ V}$	-	5	12	-	15	-	18	ns
		$V_{CC} = 6.0\text{ V}$	-	4	10	-	13	-	15	ns

Symbol	Parameter	Conditions	25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
t_W	pulse width	SHCP (HIGH or LOW); see Fig. 6								
		$V_{CC} = 2.0\text{ V}$	80	10	-	100	-	120	-	ns
		$V_{CC} = 4.5\text{ V}$	16	4	-	20	-	24	-	ns
		$V_{CC} = 6.0\text{ V}$	14	3	-	17	-	20	-	ns
		STCP (HIGH or LOW); see Fig. 7								
		$V_{CC} = 2.0\text{ V}$	80	10	-	100	-	120	-	ns
		$V_{CC} = 4.5\text{ V}$	16	4	-	20	-	24	-	ns
		$V_{CC} = 6.0\text{ V}$	14	3	-	17	-	20	-	ns
		SHR and STR (HIGH or LOW); see Fig. 10 and Fig. 11								
		$V_{CC} = 2.0\text{ V}$	80	14	-	100	-	120	-	ns
		$V_{CC} = 4.5\text{ V}$	16	5	-	20	-	24	-	ns
		$V_{CC} = 6.0\text{ V}$	14	4	-	17	-	20	-	ns
t_{su}	set-up time	DS to SHCP; see Fig. 8								
		$V_{CC} = 2.0\text{ V}$	100	10	-	125	-	150	-	ns
		$V_{CC} = 4.5\text{ V}$	20	4	-	25	-	30	-	ns
		$V_{CC} = 6.0\text{ V}$	17	3	-	21	-	26	-	ns
		SHR to STCP; see Fig. 9								
		$V_{CC} = 2.0\text{ V}$	100	14	-	125	-	150	-	ns
		$V_{CC} = 4.5\text{ V}$	20	5	-	25	-	30	-	ns
		$V_{CC} = 6.0\text{ V}$	17	4	-	21	-	26	-	ns
		SHCP to STCP; see Fig. 7								
		$V_{CC} = 2.0\text{ V}$	100	17	-	125	-	150	-	ns
		$V_{CC} = 4.5\text{ V}$	20	6	-	25	-	30	-	ns
		$V_{CC} = 6.0\text{ V}$	17	5	-	21	-	26	-	ns
t_h	hold time	DS to SHCP; see Fig. 8								
		$V_{CC} = 2.0\text{ V}$	25	-8	-	30	-	35	-	ns
		$V_{CC} = 4.5\text{ V}$	5	-3	-	6	-	7	-	ns
		$V_{CC} = 6.0\text{ V}$	4	-2	-	5	-	6	-	ns
t_{rec}	recovery time	SHR to SHCP and STR to STCP; see Fig. 10 and Fig. 11								
		$V_{CC} = 2.0\text{ V}$	50	-14	-	65	-	75	-	ns
		$V_{CC} = 4.5\text{ V}$	10	-5	-	13	-	15	-	ns
		$V_{CC} = 6.0\text{ V}$	9	-4	-	11	-	13	-	ns

Symbol	Parameter	Conditions	25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
f _{max}	maximum frequency	SHCP or STCP; see Fig. 6 and Fig. 7								
		V _{CC} = 2.0 V	6.0	30	-	4.8	-	4.0	-	MHz
		V _{CC} = 4.5 V	30	92	-	24	-	20	-	MHz
		V _{CC} = 5.0 V; C _L = 15 pF	-	100	-	-	-	-	-	MHz
		V _{CC} = 6.0 V	35	109	-	28	-	24	-	MHz
C _{PD}	power dissipation capacitance	V _I = GND to V _{CC} ; V _{CC} = 5 V; [2] f _i = 1 MHz	-	84	-	-	-	-	-	pF

[1] t_{pd} is the same as t_{PHL} and t_{PLH}.

[2] C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

$\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

Table 9. Dynamic characteristics type 74HCT594-Q100

GND = 0 V; V_{CC} = 4.5 V; t_r = t_f = 6 ns; C_L = 50 pF; For test circuit see Fig. 12.

Symbol	Parameter	Conditions	25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
t _{pd}	propagation delay	SHCP to Q7S; see Fig. 6 [1]	-	18	32	-	40	-	48	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	15	-	-	-	-	-	ns
		STCP to Qn; see Fig. 7	-	18	32	-	40	-	48	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	15	-	-	-	-	-	ns
t _{PHL}	HIGH to LOW propagation delay	SHR to Q7S; see Fig. 10	-	17	30	-	38	-	45	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	14	-	-	-	-	-	ns
		STR to Qn; see Fig. 11	-	17	30	-	38	-	45	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	14	-	-	-	-	-	ns
t _{THL}	HIGH to LOW output transition time	Q7S; see Fig. 6								
		V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
		Qn								
		V _{CC} = 4.5 V	-	5	12	-	15	-	18	ns
t _{TLH}	LOW to HIGH output transition time	Q7S; see Fig. 6								
		V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
		Qn								
		V _{CC} = 4.5 V	-	5	12	-	15	-	18	ns
t _w	pulse width	SHCP (HIGH or LOW); see Fig. 6	16	4	-	20	-	24	-	ns
		STCP (HIGH or LOW); see Fig. 7	16	4	-	20	-	24	-	ns
		SHR and STR (HIGH or LOW); see Fig. 10 and Fig. 11	16	6	-	20	-	24	-	ns

Symbol	Parameter	Conditions	25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
t _{su}	set-up time	DS to SHCP; see Fig. 8	20	4	-	25	-	30	-	ns
		SHR to STCP; see Fig. 9	20	6	-	25	-	30	-	ns
		SHCP to STCP; see Fig. 7	20	7	-	25	-	30	-	ns
t _h	hold time	DS to SHCP; see Fig. 8	5	-3	-	6	-	7	-	ns
t _{rec}	recovery time	SHR to SHCP and STR to STCP; see Fig. 10 and Fig. 11	10	-5	-	13	-	15	-	ns
f _{max}	maximum frequency	SHCP or STCP; see Fig. 6 and Fig. 7	30	92	-	24	-	20	-	MHz
		V _{CC} = 5.0 V; C _L = 15 pF	-	100	-	-	-	-	-	MHz
C _{PD}	power dissipation capacitance	V _I = GND to V _{CC} - 1.5 V; V _{CC} = 5 V; f _i = 1 MHz [2]	-	89	-	-	-	-	-	pF

[1] t_{pd} is the same as t_{PHL} and t_{PLH}.

[2] C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz;

f_o = output frequency in MHz;

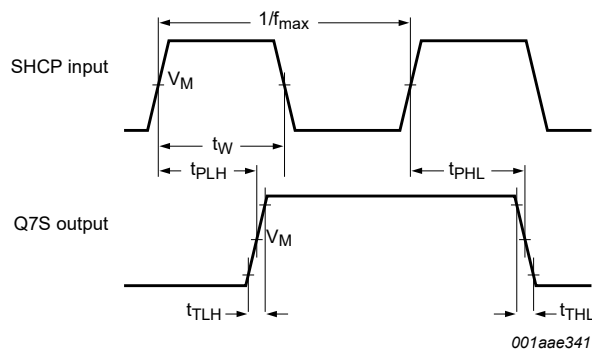
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

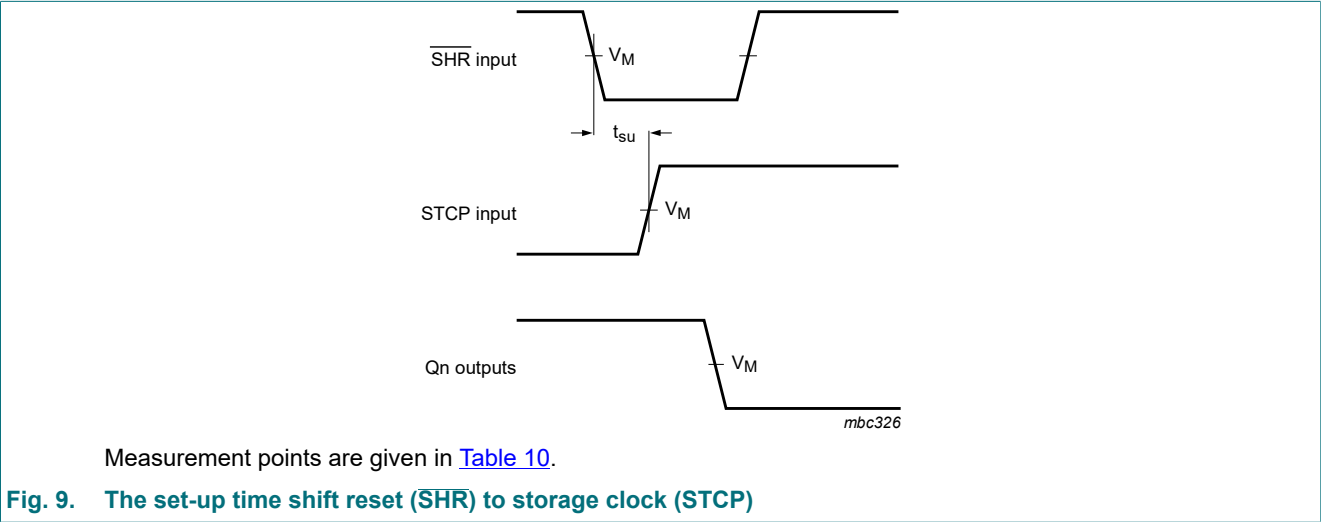
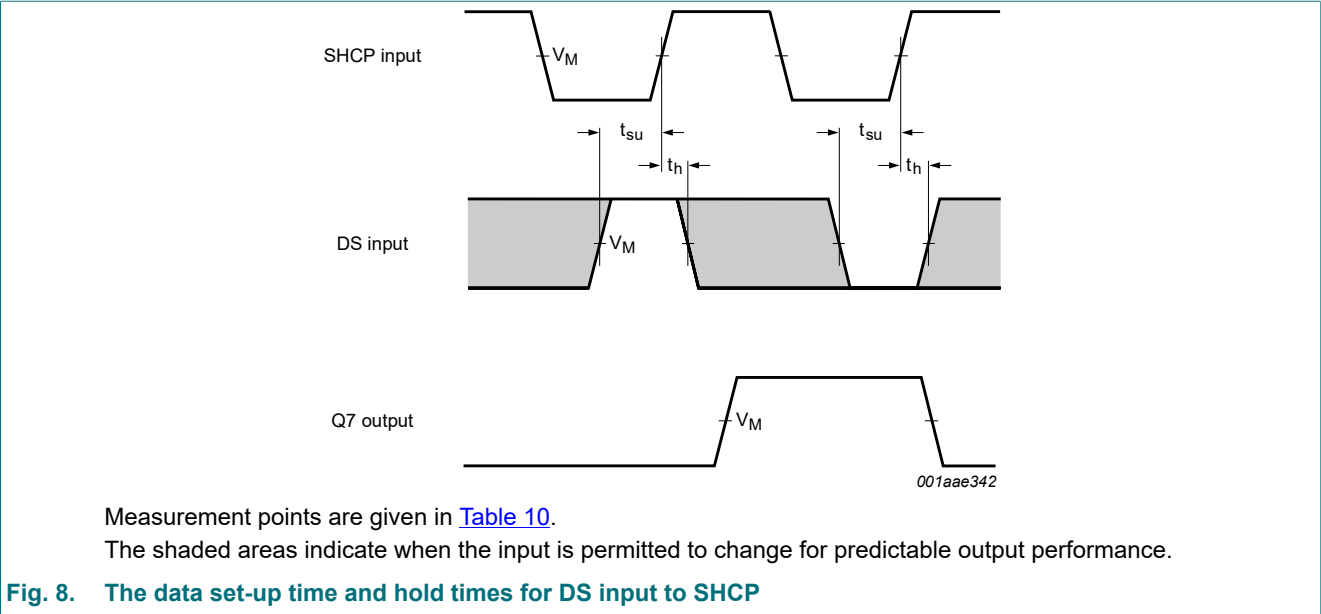
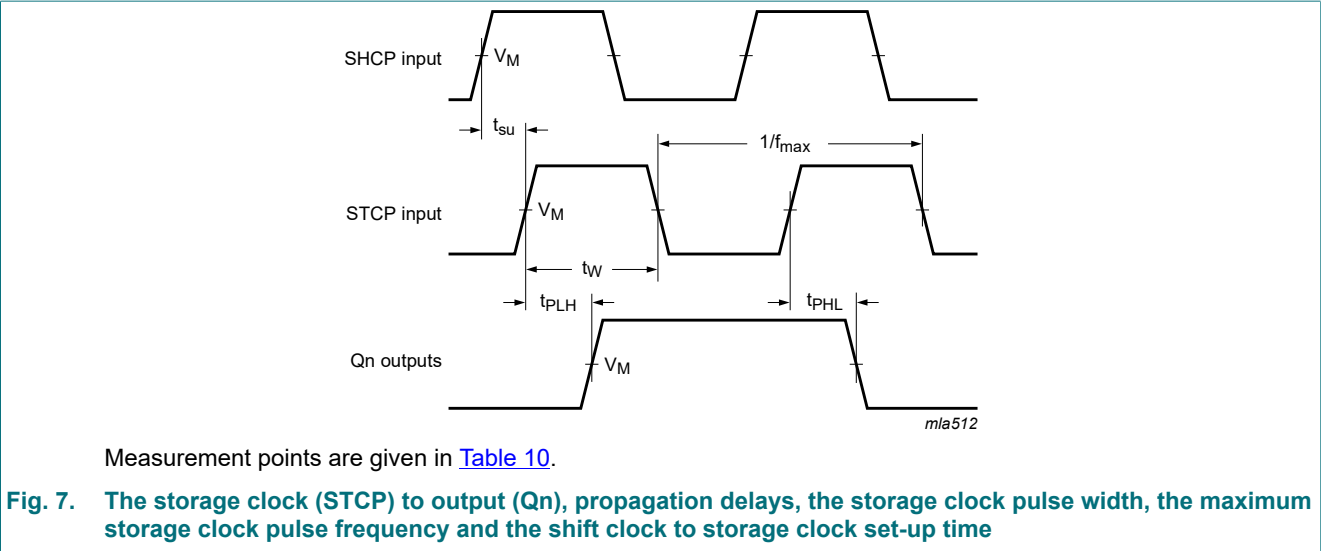
$\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

11.1. Waveforms and test circuit



Measurement points are given in Table 10.

Fig. 6. The shift clock (SHCP) to output (Q7S) propagation delays, the shift clock pulse width, the maximum shift clock frequency, and output transition times



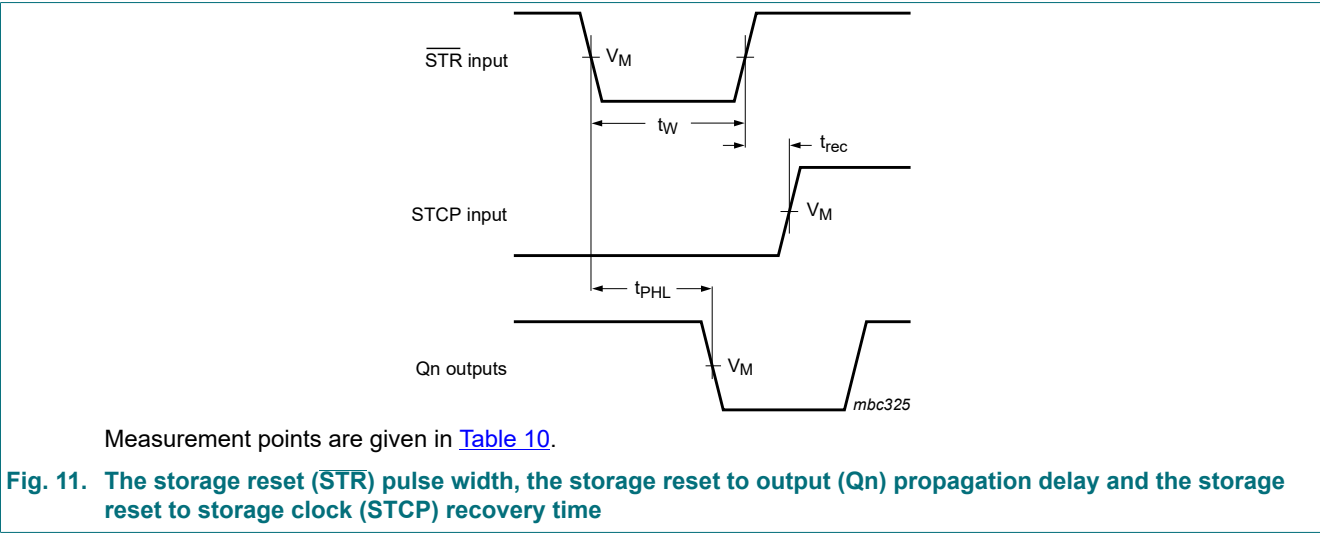
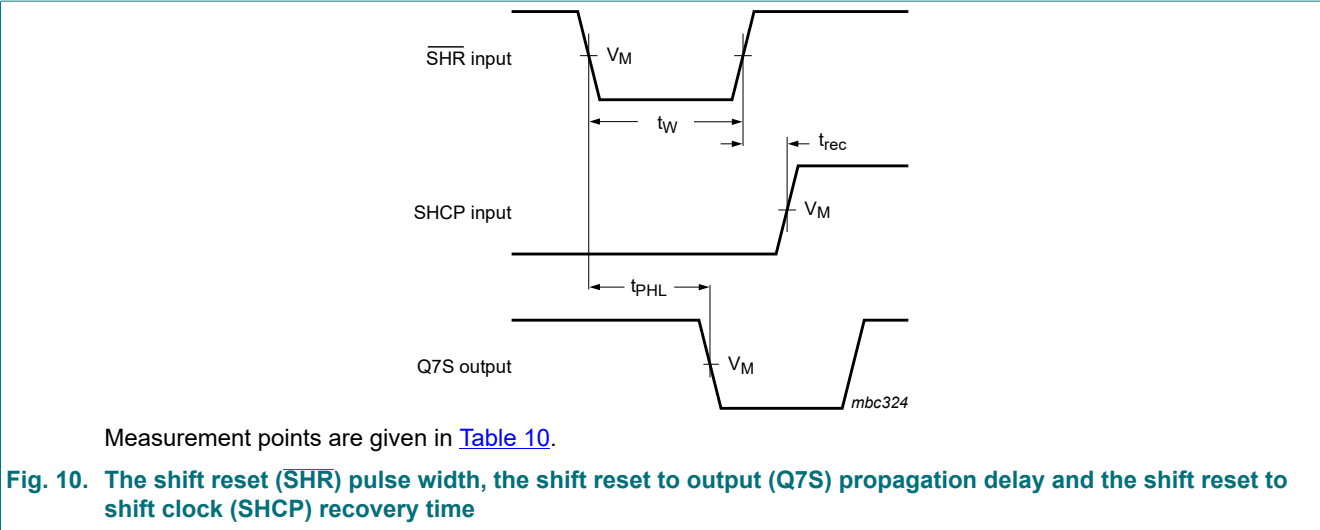


Table 10. Measurement points

Type	Input	Output
	V_M	V_M
74HC594-Q100	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
74HCT594-Q100	1.3 V	1.3 V

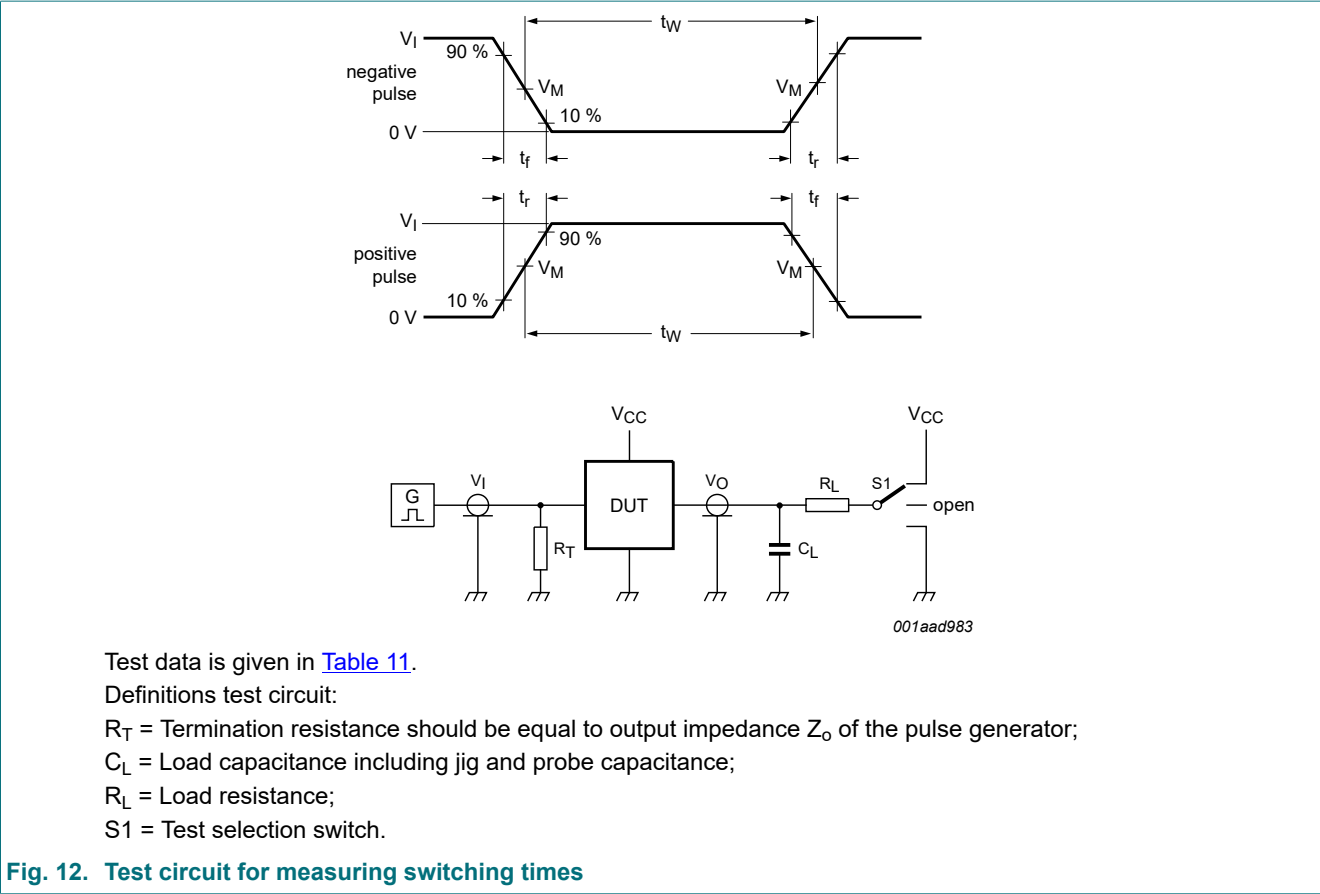


Table 11. Test data

Type	Input		Load		S1 position		
	V_I	t_r, t_f	C_L	R_L	t_{PHL}, t_{PLH}	t_{PZH}, t_{PHZ}	t_{PZL}, t_{PLZ}
74HC594-Q100	V_{CC}	6 ns	15 pF, 50 pF	1 k Ω	open	GND	V_{CC}
74HCT594-Q100	3 V	6 ns	15 pF, 50 pF	1 k Ω	open	GND	V_{CC}

12. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1

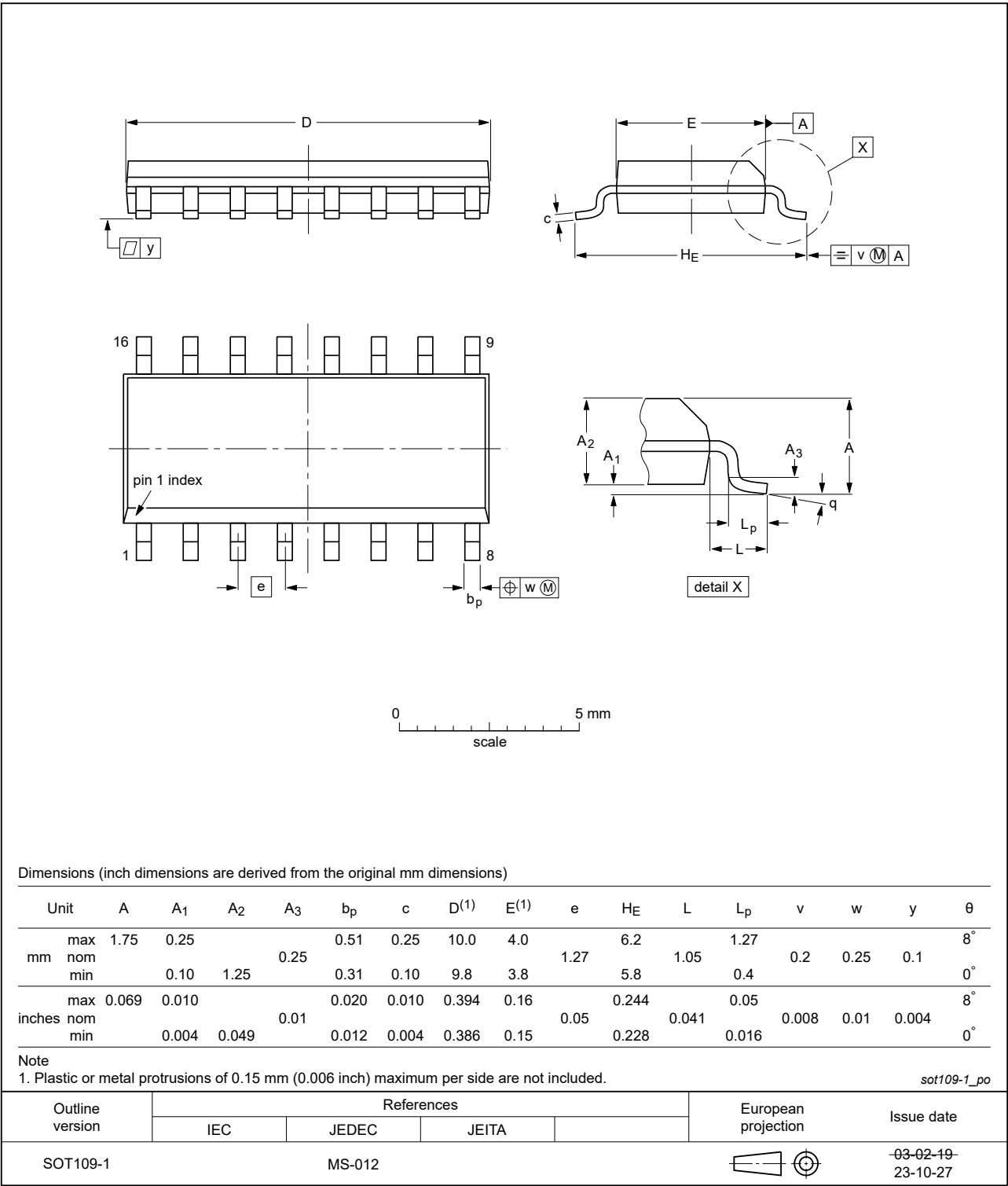


Fig. 13. Package outline SOT109-1 (SO16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1

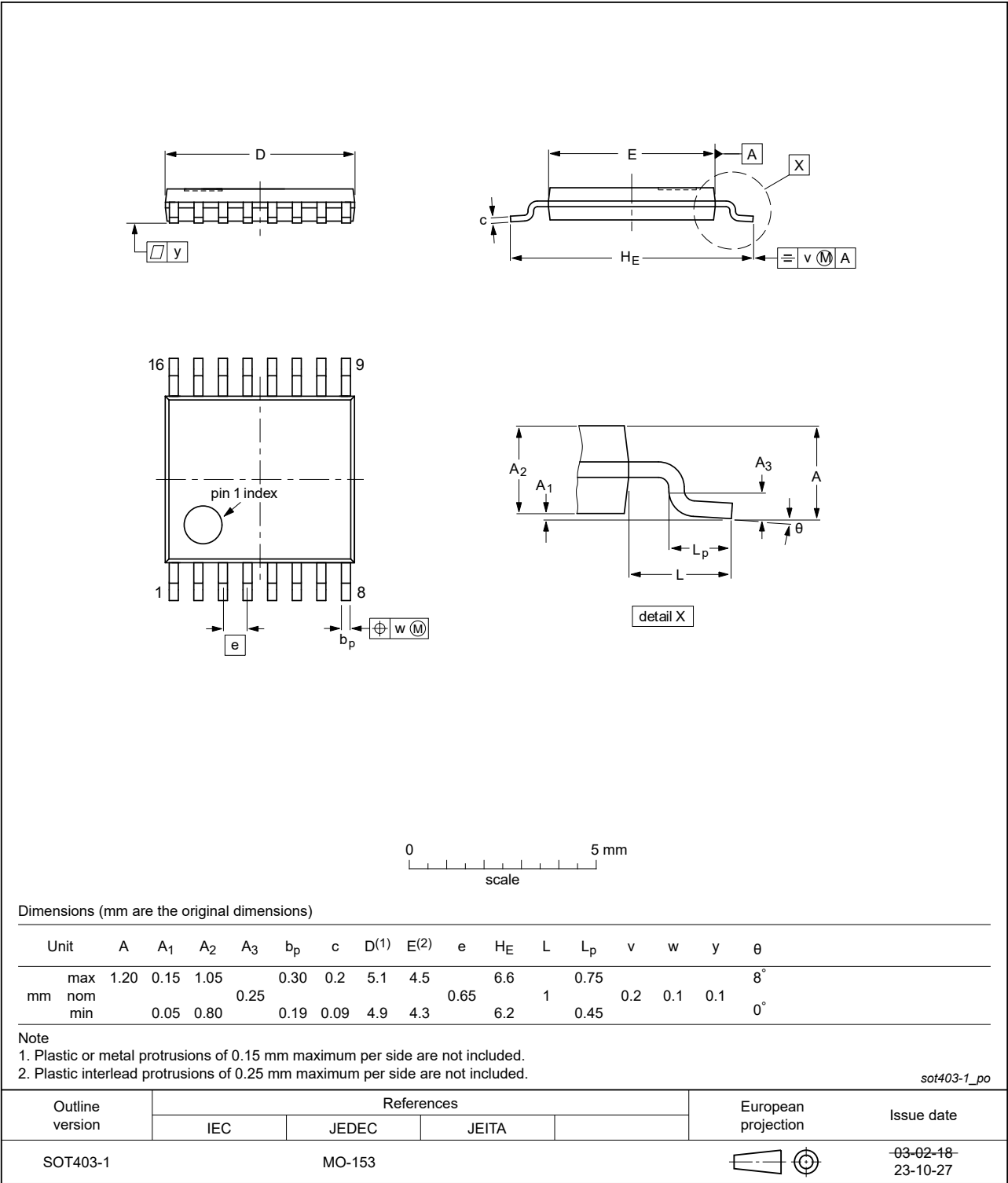


Fig. 14. Package outline SOT403-1 (TSSOP16)

DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads;
16 terminals; body 2.5 x 3.5 x 0.85 mm

SOT763-1

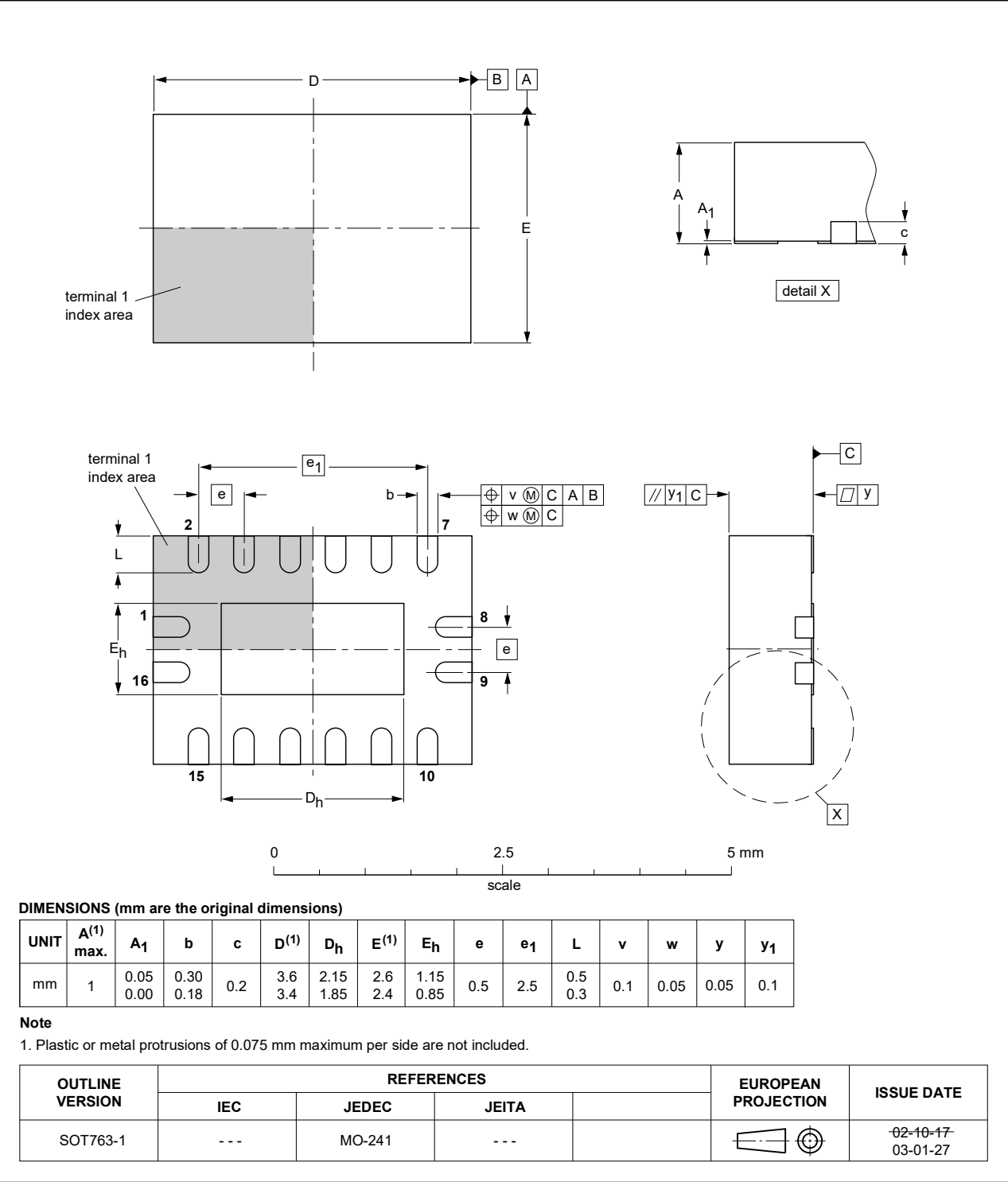


Fig. 15. Package outline SOT763-1 (DHVQFN16)

13. Abbreviations

Table 12. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT594_Q100 v.5	20240319	Product data sheet	-	74HC_HCT594_Q100 v.4
Modifications:	- Section 2: ESD specification updated according to the latest JEDEC standard. - Fig. 13 and Fig. 14: Aligned SO and TSSOP package outline drawings to JEDEC MS-012 and MO-153.			
74HC_HCT594_Q100 v.4	20220927	Product data sheet	-	74HC_HCT594_Q100 v.3
Modifications:	Type number 74HC594BQ-Q100 (SOT763-1/DHVQFN16) added.			
74HC_HCT594_Q100 v.3	20210812	Product data sheet	-	74HC_HCT594_Q100 v.2
Modifications:	- The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. - Legal texts have been adapted to the new company name where appropriate. - Section 1 and Section 2 updated. - Section 8: Derating values for P_{tot} total power dissipation updated. - Section 9: rise time and fall time replaced by input transition rise and fall rate.			
74HC_HCT594_Q100 v.2	20160613	Product data sheet	-	74HC_HCT594_Q100 v.1
Modifications:	Added type number 74HC594PW-Q100 (SOT403-1).			
74HC_HCT594_Q100 v.1	20120802	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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